

# ANALOG



# ELECTRONICS

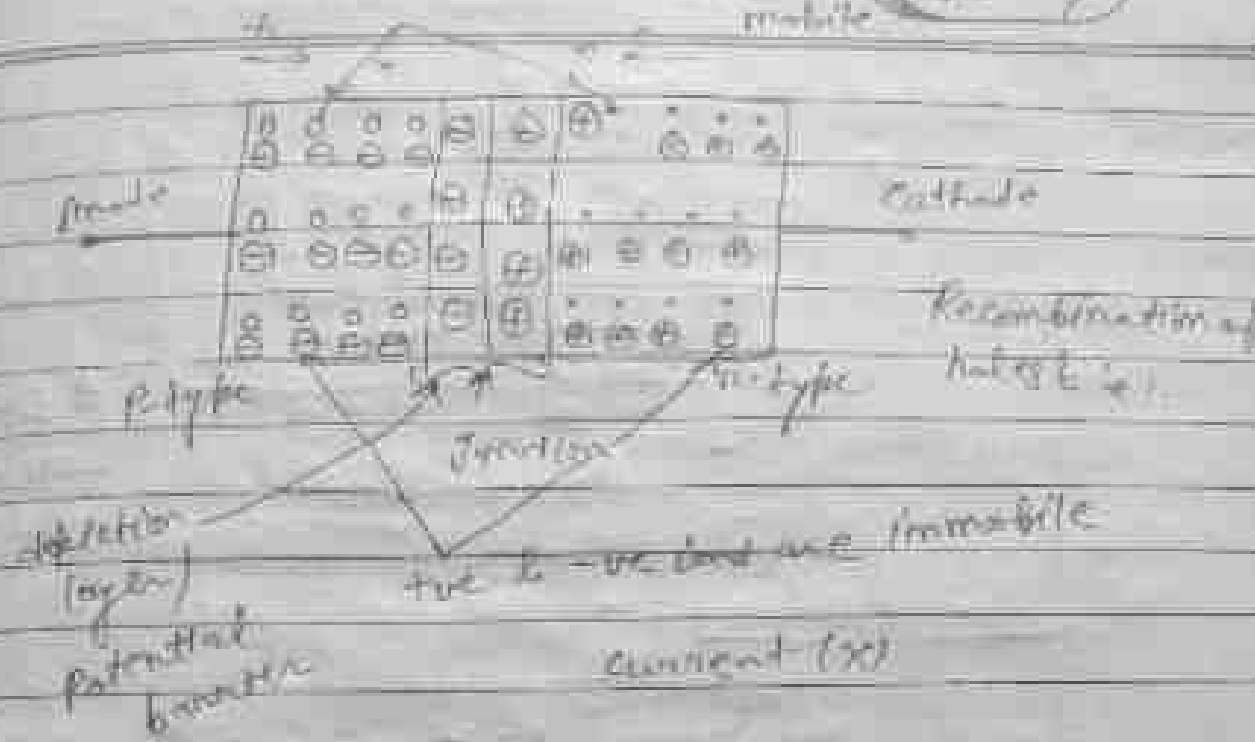
2<sup>nd</sup> Semester

Handwritten Notes

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Page 1 of 46

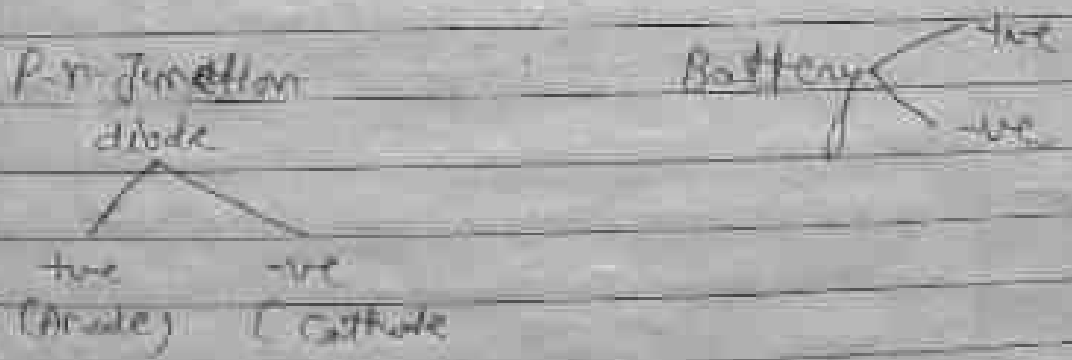
- Abhay Gupta  
(B.Sc. Polytechnic  
Gwalior)

holes to electrons are mobile

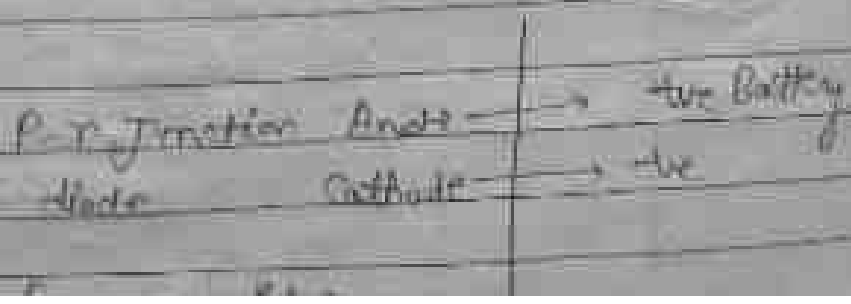


Biasing: It is the process in which P-N Junction diode connected with external source of energy / battery.

- Biasing in P-N Junction diode
- (i) Forward Biasing
  - (ii) Reverse Biasing



Forward Biasing :-



## Forward Bias

A  $\rightarrow$  +ve , C  $\rightarrow$  -ve  
Depletion layer decreases

## Forward Breakdown

It is caused due to Majority Charge carriers.

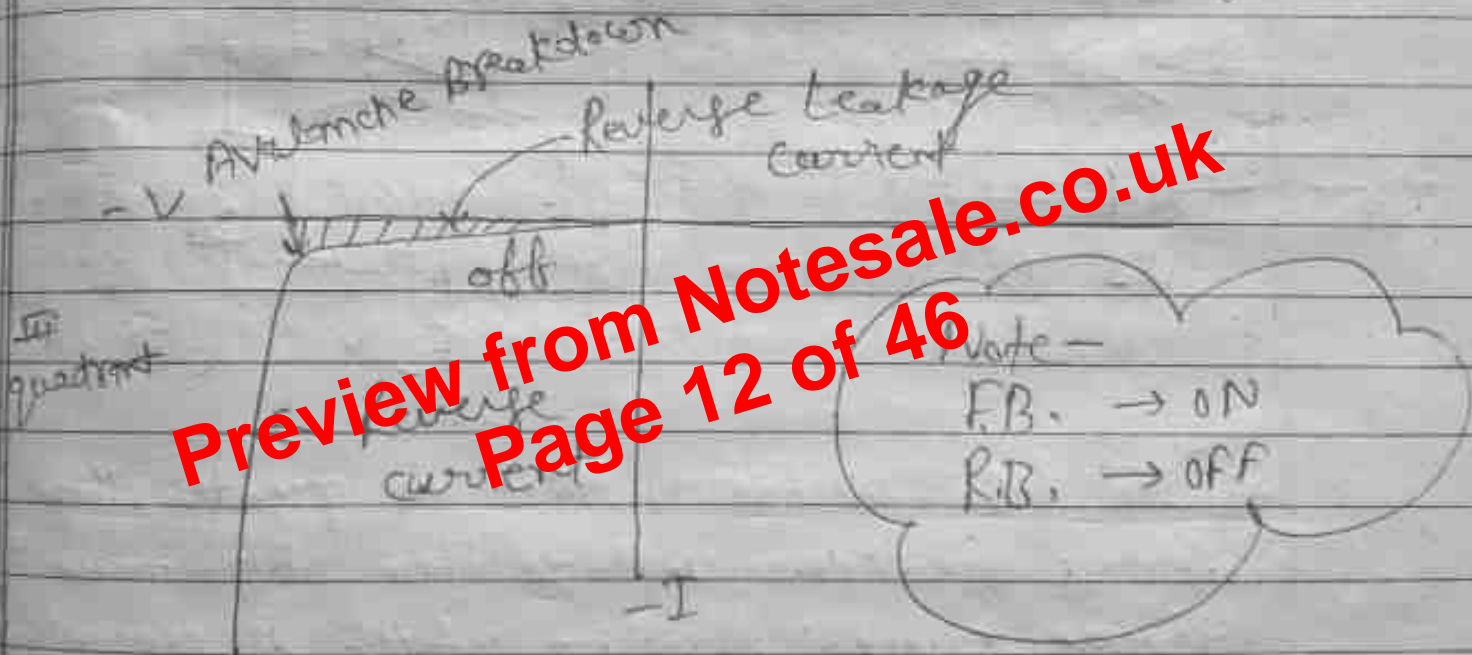
## Reverse Bias

(i) A  $\rightarrow$  -ve , C  $\rightarrow$  +ve  
(ii) Depletion layer increases

## Reverse / Avalanche Breakdown

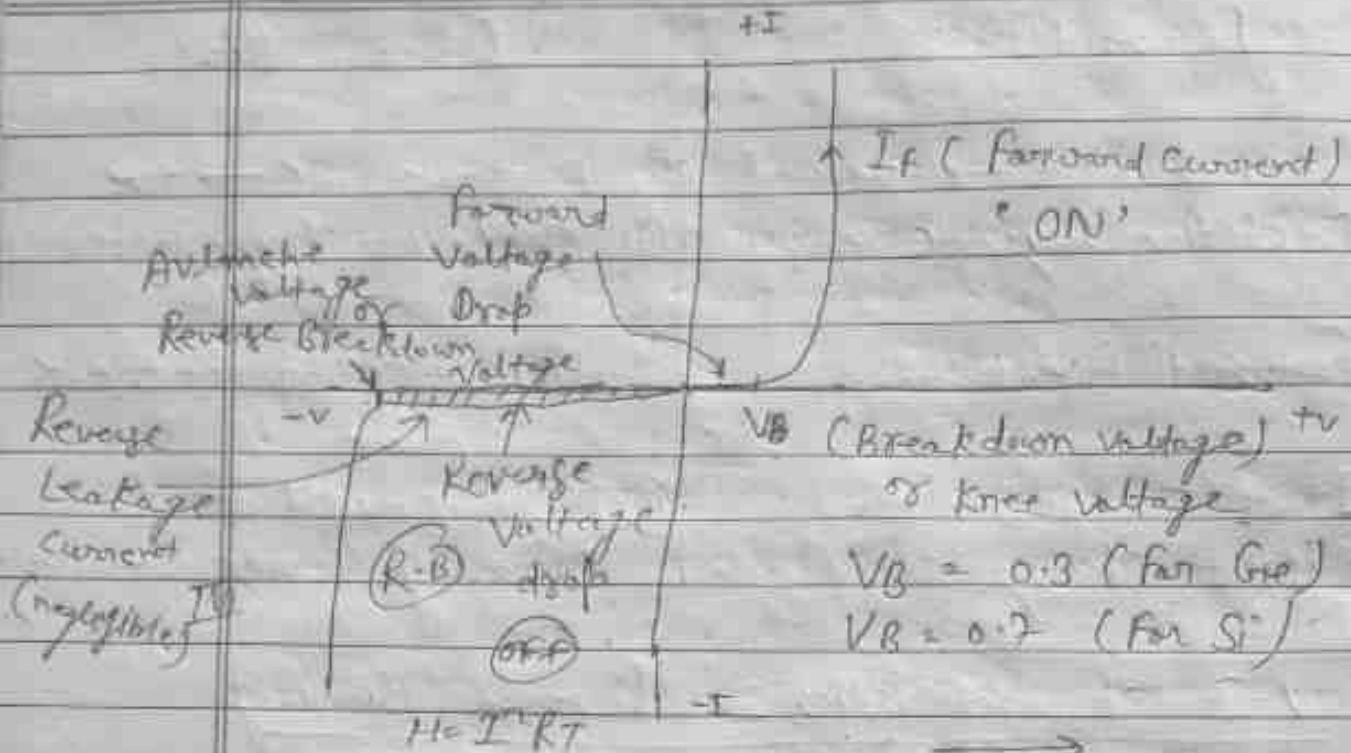
(iv) It is caused due to Minority Charge Carriers

## V-I characteristics in Reverse Biasing

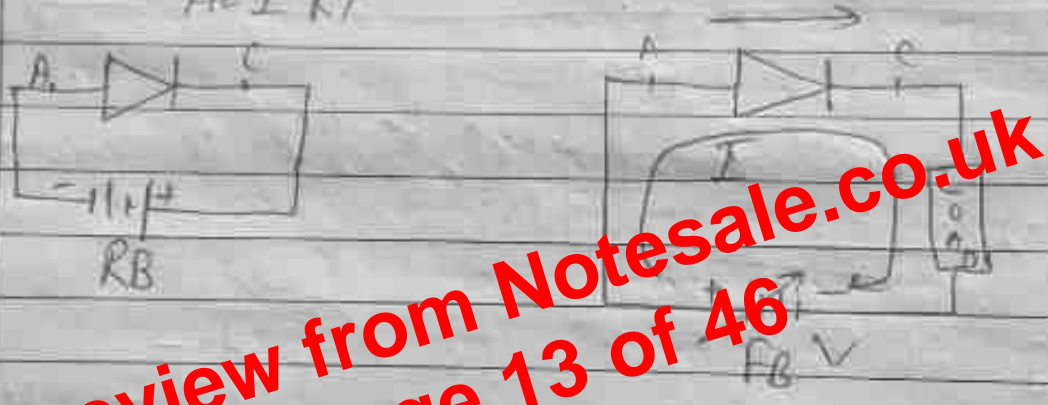


Reverse leakage current :- The current produced due to minority charge carriers in P-n junction diodes is called Reverse leakage current

## V-I characteristics



$I_f$  (Forward Current)  
'ON'  
 $V_B$  (Breakdown voltage) or knee voltage  
 $V_B = 0.3$  (for Ge)  
 $V_B = 0.7$  (for Si)



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Page 13 of 46

\* In R.B., when voltage is greater than Reverse Breakdown voltage then high amount of reverse current produce which is uncontrollable. So we should always remember that voltage should not become greater than R.V.B.

\* Voltage drop in R.B. is greater than in F.B. because of minority charge carriers.

* F.B.	R.B.
ON	OFF
Voltage drop ↓	Voltage drop ↑
due to majority	due to minority

## Resistance of P-n Junction diode :-

- ① Static Resistance      ② Dynamic Resistance

Static Resistance :- If P-n Junction diode connected with dc current then the produced resistance is called Static Resistance.

$$R_{dc} = \frac{V_D}{I_D}$$

② Dynamic Resistance :- If the value of AC current is faster than average current then the produced resistance is called Dynamic Resistance.

$$r_{ac} = \frac{\Delta V_D}{\Delta I_D}$$

Change in diode voltage  
Change in diode current

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Page 18 of 46

## Use of P-n Junction diode as Rectifier

Rectifier Circuit  $\rightarrow$  Converts  $\rightarrow$  AC  $\rightarrow$  DC  
(int)

Production

AC ( $\sim$ )

DC ( $\rightarrow$ )

Rectifier :- It is a circuit which converts AC in to DC.

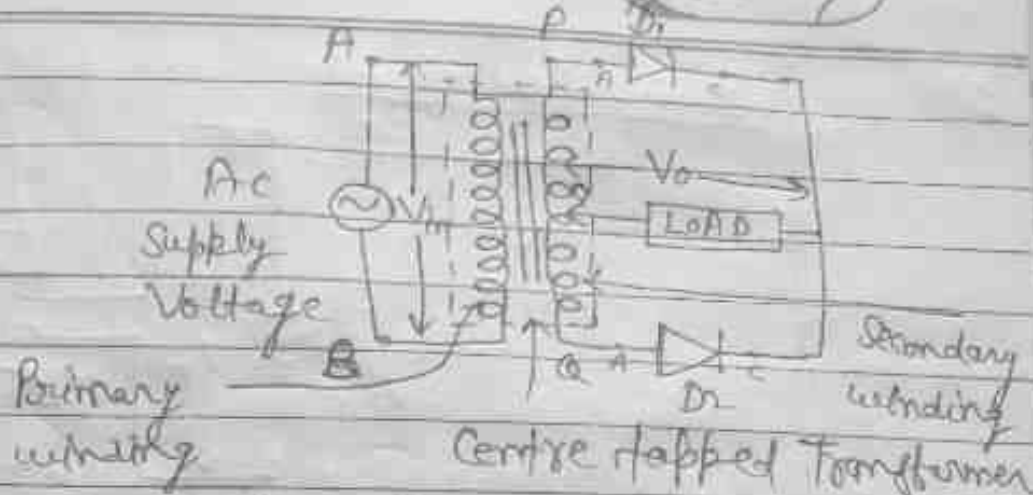
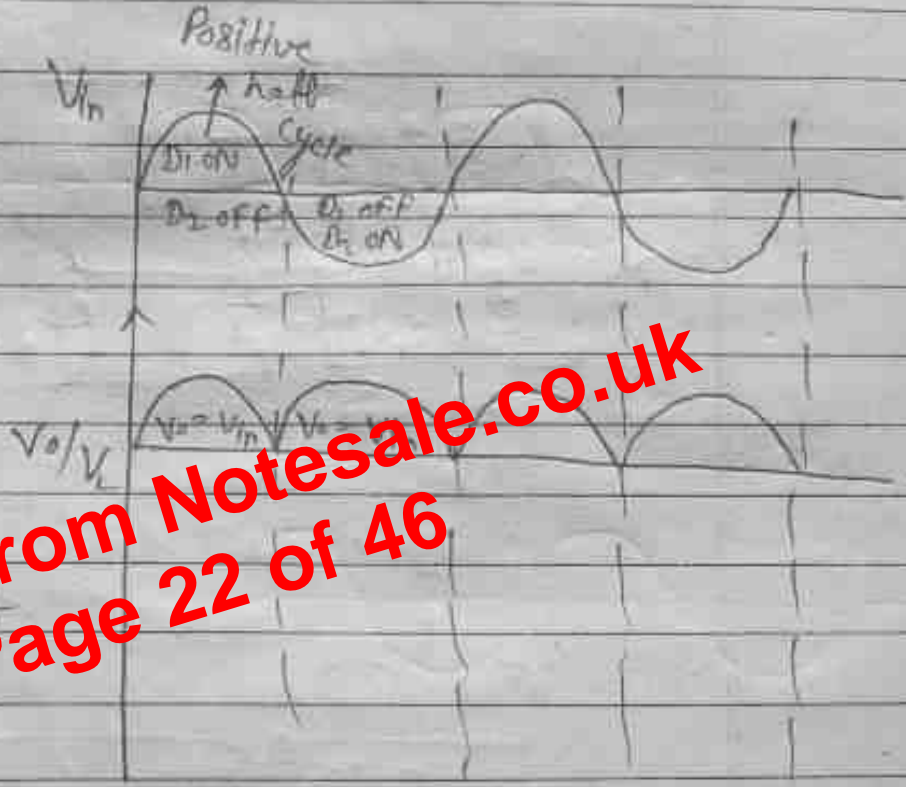


Fig: Centre Tapped full wave Rectifier.



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Page 22 of 46

\* In 1<sup>st</sup> Positive half cycle  
P (+) and Q (-)  
with respect to 0.

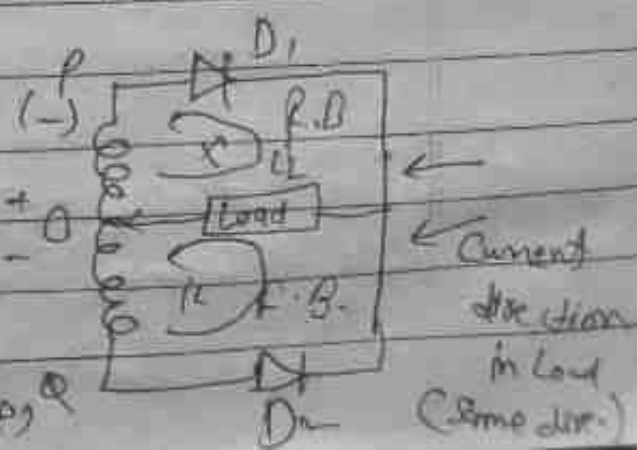
For Diode D<sub>1</sub>, P (+) & Q (-) so, D<sub>1</sub> goes in F.B.

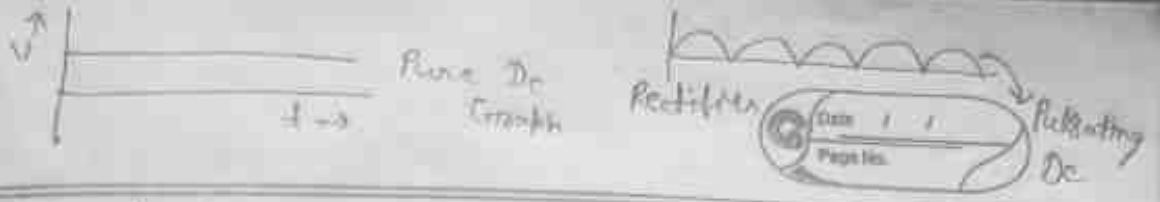
& Diode D<sub>2</sub>, Q (-) & P (+) so, D<sub>2</sub> goes in R.B.

\* In 1<sup>st</sup> Negative half cycle

For Diode D<sub>1</sub>, P (-), Q (-) so  
D<sub>1</sub> goes in R.B.

& Diode D<sub>2</sub>, Q (+), P (-)  
so D<sub>2</sub> goes in F.B.





Filter:- The filter circuit is necessary for smoothing of the voltage obtained by the rectifier.

Capacitor connected only in parallel. So it is also called Shunt Filter.

Inductor connected in Series.

Filter circuit:- It is an A.C. circuit that filters the input signal to desired output signal.

### \* Types of Filter circuit

(i) C-Filter

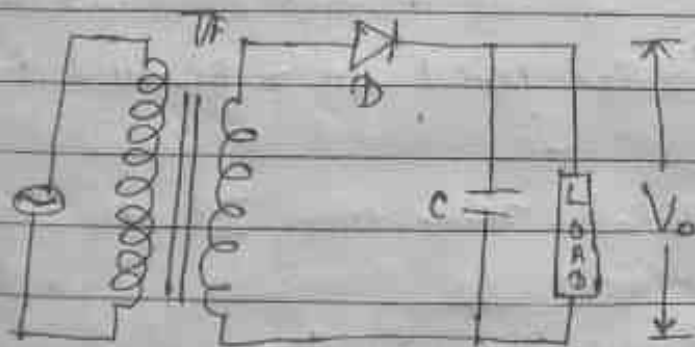
(ii) L-Filter

(iii) LC-Filter

(iv) C-Filter circuit

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Page 32 of 46

### \* For Half wave Rectifier



with filter

